



DMG4822SSD

Product Summary

| BV _{DSS} | R _{DS(ON)} max | I _D max T _A = +25°C |
|-------------------|------------------------------|--|
| 30V | 20mΩ @ V _{GS} = 10V | 10A |

Description

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Power Management Functions
- DC-DC Converters
- Analog Switch

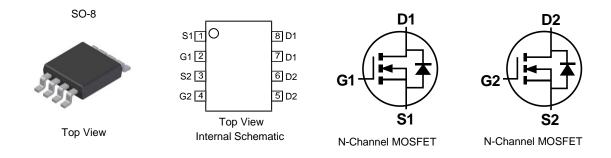
DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Low Input/Output Leakage
- Low Gate Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMG4822SSDQ</u>)

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208⁽⁴⁾
- Weight: 0.072 grams (Approximate)



Ordering Information (Note 4)

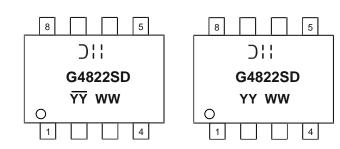
| Part Number | | Case | Packaging | | | |
|--|---------------|------------------------------|-----------|--|--|--|
| | DMG4822SSD-13 | SD-13 SO-8 2,500/Tape & Reel | | | | |
| Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. | | | | | | |

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



):: = Manufacturer's Marking G4822SD = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 19 = 2019) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|---|-----------------|--|------------------|-----------|------|
| Drain-Source Voltage | | | V _{DSS} | 30 | V |
| Gate-Source Voltage | | | V _{GSS} | ±25 | V |
| Continuous Drain Current (Note 5) V _{GS} = 10V | Steady State | T _A = +25°C T _A = +85°C | ID | 10 6.6 | A |
| Pulsed Drain Current (Note 6) | | | I _{DM} | 60 | А |
| Avalanche Current (Notes 7 & 8) | | | I _{AR} | 1.68 | А |
| Repetitive Avalanche Energy L = 0.3mH (Notes 7 & 8) | | | E _{AR} | 12.8 | mJ |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) | PD | 1.42 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{θJA} | 88.4 | °C/W |
| Operating and Storage Temperature Range | T _{J,} T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-----|-------|------|-------|---|--|
| OFF CHARACTERISTICS (Note 9) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 30 | — | _ | V | $V_{GS} = 0V, I_D = 250 \mu A$ | |
| Zero Gate Voltage Drain Current | IDSS | | — | 1 | μA | $V_{DS} = 30V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | | _ | ±100 | nA | $V_{GS} = \pm 25V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 9) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 1 | | 3 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | | | 13.4 | 20 | mΩ | $V_{GS} = 10V, I_D = 8.5A$ | |
| | R _{DS(ON)} | | 19.5 | 31 | 11152 | $V_{GS} = 4.5V, I_D = 6A$ | |
| Forward Transfer Admittance | Y _{fs} | _ | 20 | _ | mS | $V_{DS} = 5V, I_D = 8.5A$ | |
| Diode Forward Voltage | V _{SD} | _ | 0.4 | 1.0 | V | $V_{GS} = 0V, I_S = 1A$ | |
| DYNAMIC CHARACTERISTICS (Note 10) | | | | | | | |
| Input Capacitance | Ciss | | 478.9 | — | pF | | |
| Output Capacitance | Coss | | 96.7 | _ | pF | $V_{DS} = 16V, V_{GS} = 0V,$ f = 1MHz | |
| Reverse Transfer Capacitance | Crss | _ | 61.4 | — | pF | | |
| Gate Resistance | Rg | _ | 1.1 | _ | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | _ | 5 | — | nC | | |
| Total Gate Charge (V _{GS} = 10V) | Qg | _ | 10.5 | — | nC | V _{GS} = 10V, V _{DS} = 15V, | |
| Gate-Source Charge | Q _{gs} | — | 1.8 | — | nC | I _D = 8.5A | |
| Gate-Drain Charge | Q _{gd} | _ | 1.6 | — | nC | 7 | |
| Turn-On Delay Time | t _{D(ON)} | _ | 2.9 | — | ns | | |
| Turn-On Rise Time | t _R | _ | 7.9 | — | ns | V _{DS} = 15V, V _{GS} = 10V, | |
| Turn-Off Delay Time | tD(OFF) | _ | 14.6 | — | ns | $R_L = 1.8\Omega, R_G = 3\Omega$ | |
| Turn-Off Fall Time | t _F | | 3.1 | _ | ns |] | |

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.

6. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.

7. Repetitive rating, pulse width limited by junction temperature.

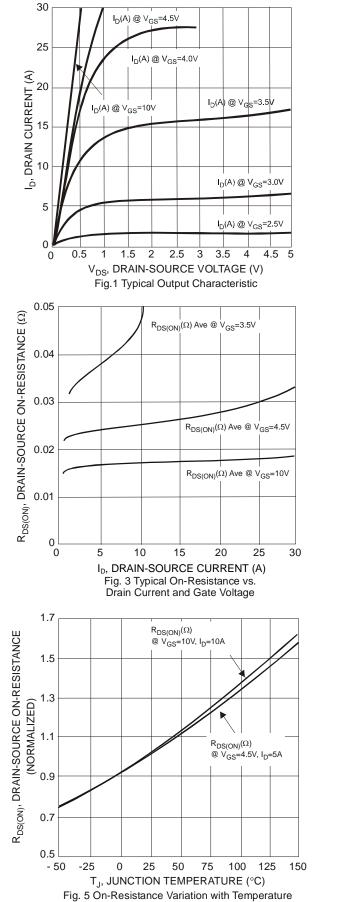
8. I_{AR} and E_{AR} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

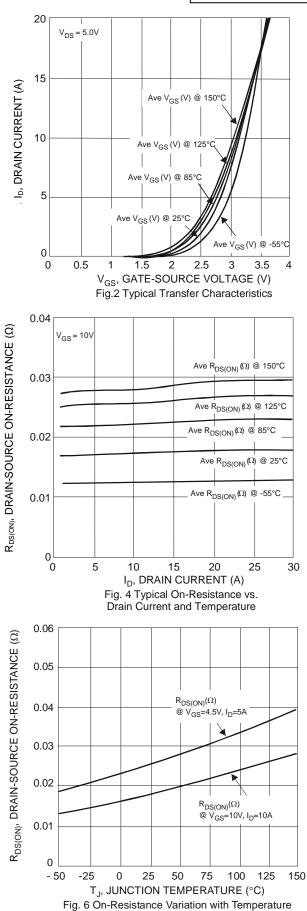
9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.



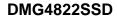
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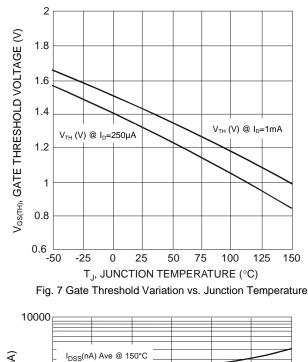


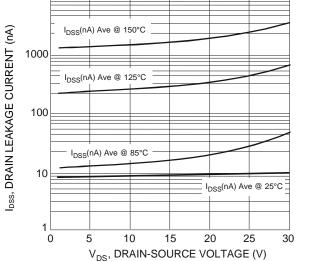


NEW PRODUCT

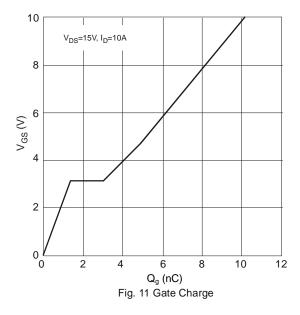


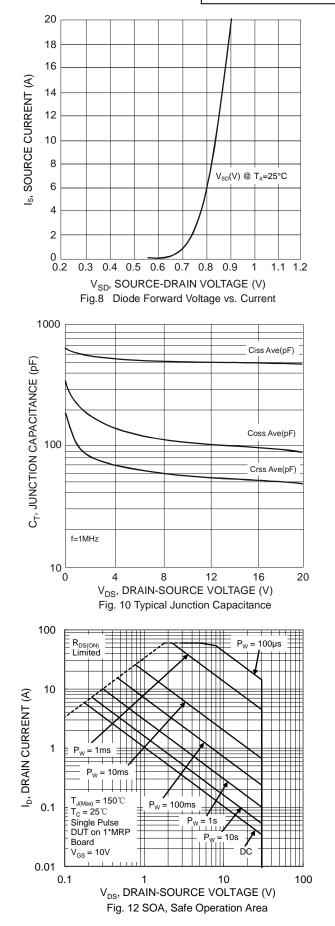






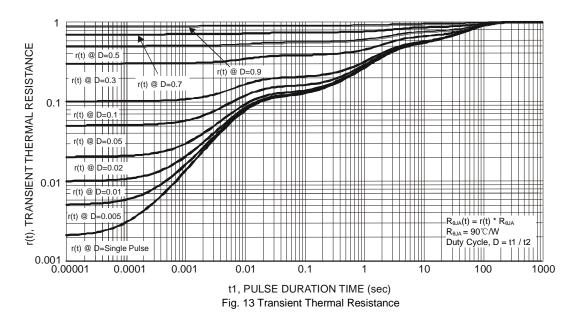






DMG4822SSD Document number: DS35403 Rev. 3 - 2



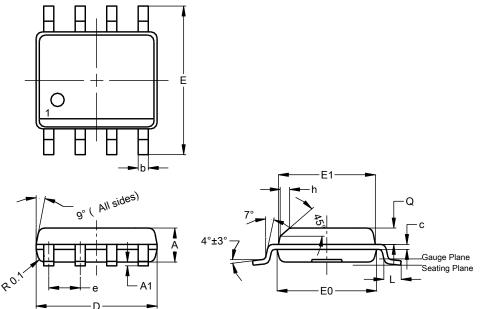




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

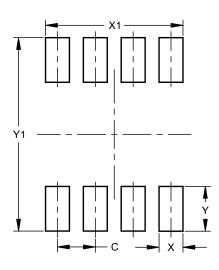
SO-8



| SO-8 | | | | | | |
|----------------------|------|------|------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 1.40 | 1.50 | 1.45 | | | |
| A1 | 0.10 | 0.20 | 0.15 | | | |
| b | 0.30 | 0.50 | 0.40 | | | |
| C | 0.15 | 0.25 | 0.20 | | | |
| D | 4.85 | 4.95 | 4.90 | | | |
| ш | 5.90 | 6.10 | 6.00 | | | |
| E1 | 3.80 | 3.90 | 3.85 | | | |
| E0 | 3.85 | 3.95 | 3.90 | | | |
| е | | | 1.27 | | | |
| h | - | - | 0.35 | | | |
| L | 0.62 | 0.82 | 0.72 | | | |
| q | 0.60 | 0.70 | 0.65 | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



| Dimensions | Value (in mm) | | | |
|------------|---------------|--|--|--|
| С | 1.27 | | | |
| Х | 0.802 | | | |
| X1 | 4.612 | | | |
| Y | 1.505 | | | |
| Y1 | 6.50 | | | |

NEW PRODUCT

R0.1.

SO-8



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